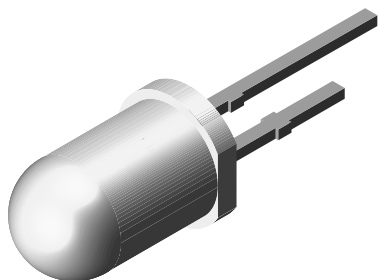




## High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology



### FEATURES

- Package type: leaded
- Package form: T-1 $\frac{3}{4}$
- Dimensions (in mm):  $\varnothing$  5
- Leads with stand-off
- Peak wavelength:  $\lambda_p = 850$  nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity:  $\phi = \pm 10^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
**GREEN**  
(5-2008)

### DESCRIPTION

TSHG5210 is an infrared, 850 nm emitting diode based on surface emitter chip technology with high radiant power and high speed, molded in a clear, untinted plastic package.

### APPLICATIONS

- Infrared high speed remote control and free air data transmission systems with high modulation frequencies or high data transmission rate requirements
- Transmission systems according to IrDA requirements and for carrier frequency based systems (e.g. ASK/FSK - coded, 450 kHz or 1.3 MHz)

### PRODUCT SUMMARY

| COMPONENT | $I_e$ (mW/sr) | $\phi$ (°) | $\lambda_p$ (nm) | $t_r$ (ns) |
|-----------|---------------|------------|------------------|------------|
| TSHG5210  | 215           | $\pm 10$   | 850              | 10         |

#### Note

- Test conditions see table "Basic Characteristics"

### ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS                      | PACKAGE FORM      |
|---------------|-----------|------------------------------|-------------------|
| TSHG5210      | Bulk      | MOQ: 4000 pcs, 4000 pcs/bulk | T-1 $\frac{3}{4}$ |

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                              | TEST CONDITION                         | SYMBOL     | VALUE       | UNIT             |
|----------------------------------------|----------------------------------------|------------|-------------|------------------|
| Reverse voltage                        |                                        | $V_R$      | 5           | V                |
| Forward current                        |                                        | $I_F$      | 100         | mA               |
| Peak forward current                   | $t_p/T = 0.5$ , $t_p = 100$ $\mu$ s    | $I_{FM}$   | 200         | mA               |
| Surge forward current                  | $t_p = 100$ $\mu$ s                    | $I_{FSM}$  | 1           | A                |
| Power dissipation                      |                                        | $P_V$      | 180         | mW               |
| Junction temperature                   |                                        | $T_j$      | 100         | $^\circ\text{C}$ |
| Ambient temperature range              |                                        | $T_{amb}$  | -40 to +85  | $^\circ\text{C}$ |
| Storage temperature range              |                                        | $T_{stg}$  | -40 to +100 | $^\circ\text{C}$ |
| Soldering temperature                  | $t \leq 5$ s, 2 mm from case           | $T_{sd}$   | 260         | $^\circ\text{C}$ |
| Thermal resistance junction to ambient | J-STD-051, leads 7 mm, soldered on PCB | $R_{thJA}$ | 230         | K/W              |

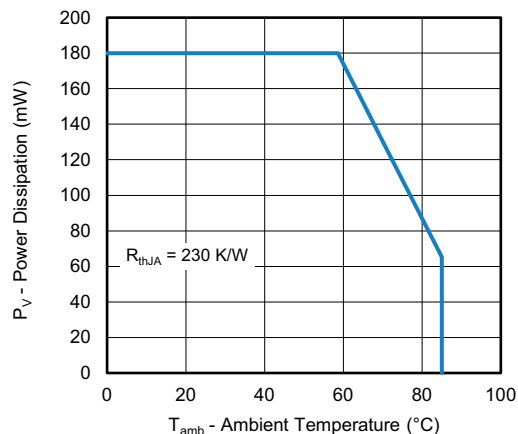


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

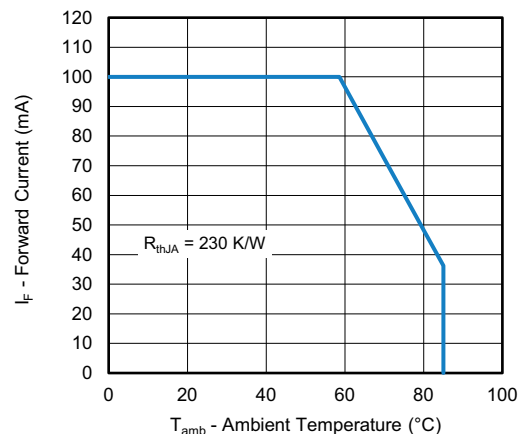


Fig. 2 - Forward Current Limit vs. Ambient Temperature

**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| PARAMETER                              | TEST CONDITION                                      | SYMBOL           | MIN.                               | TYP.     | MAX. | UNIT          |
|----------------------------------------|-----------------------------------------------------|------------------|------------------------------------|----------|------|---------------|
| Forward voltage                        | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$        | $V_F$            | -                                  | 1.6      | 1.8  | V             |
|                                        | $I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$ | $V_F$            | -                                  | 3.0      | -    | V             |
| Temperature coefficient of $V_F$       | $I_F = 100\text{ mA}$                               | $TK_{V_F}$       | -                                  | -1.5     | -    | mV/K          |
| Reverse current                        |                                                     | $I_R$            | Not designed for reverse operation |          |      | $\mu\text{A}$ |
| Junction capacitance                   | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$   | $C_j$            | -                                  | 53       | -    | pF            |
| Radiant intensity                      | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$        | $I_e$            | 100                                | 215      | 420  | mW/sr         |
|                                        | $I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$ | $I_e$            | -                                  | 1595     | -    | mW/sr         |
| Radiant power                          | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$        | $\phi_e$         | -                                  | 61       | -    | mW            |
| Temperature coefficient of $\phi_e$    | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$        | $TK_{\phi_e}$    | -                                  | -0.27    | -    | %/K           |
| Angle of half intensity                |                                                     | $\phi$           | -                                  | $\pm 10$ | -    | $^{\circ}$    |
| Peak wavelength                        | $I_F = 100\text{ mA}$                               | $\lambda_p$      | -                                  | 850      | -    | nm            |
| Spectral bandwidth                     | $I_F = 100\text{ mA}$                               | $\Delta\lambda$  | -                                  | 30       | -    | nm            |
| Temperature coefficient of $\lambda_p$ | $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$        | $TK_{\lambda_p}$ | -                                  | 0.24     | -    | nm/K          |
| Rise time                              | $I_F = 100\text{ mA}$                               | $t_r$            | -                                  | 10       | -    | ns            |
| Fall time                              | $I_F = 100\text{ mA}$                               | $t_f$            | -                                  | 10       | -    | ns            |

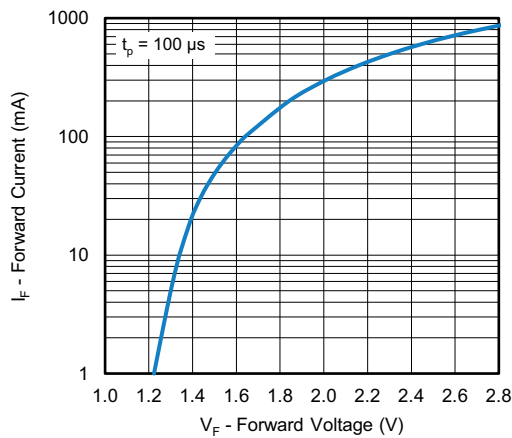
**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

Fig. 3 - Forward Current vs. Forward Voltage

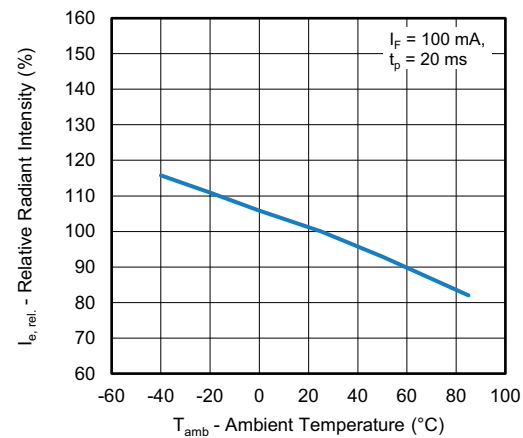


Fig. 6 - Relative Radiant Intensity vs. Forward Current

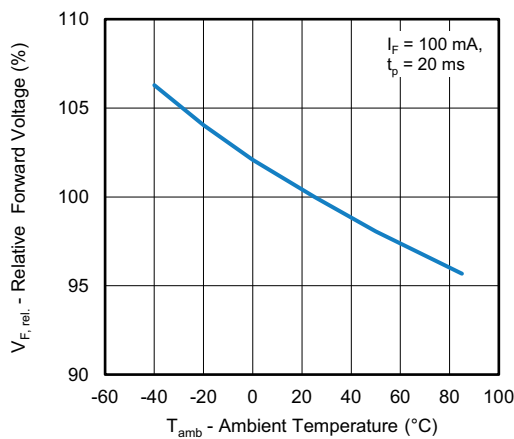


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

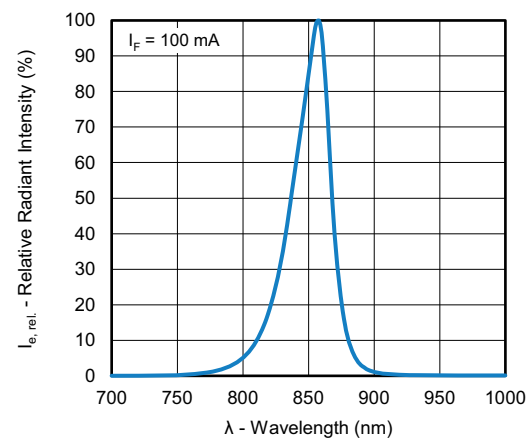


Fig. 7 - Relative Radiant Intensity vs. Wavelength

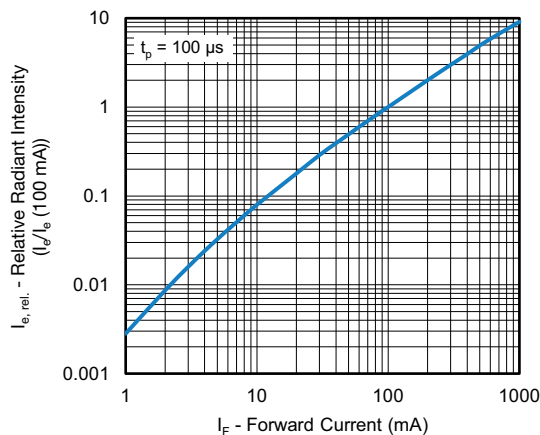


Fig. 5 - Relative Radiant Intensity vs. Forward Current

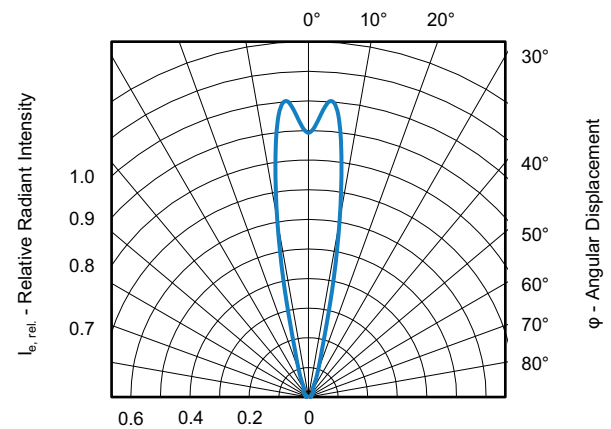
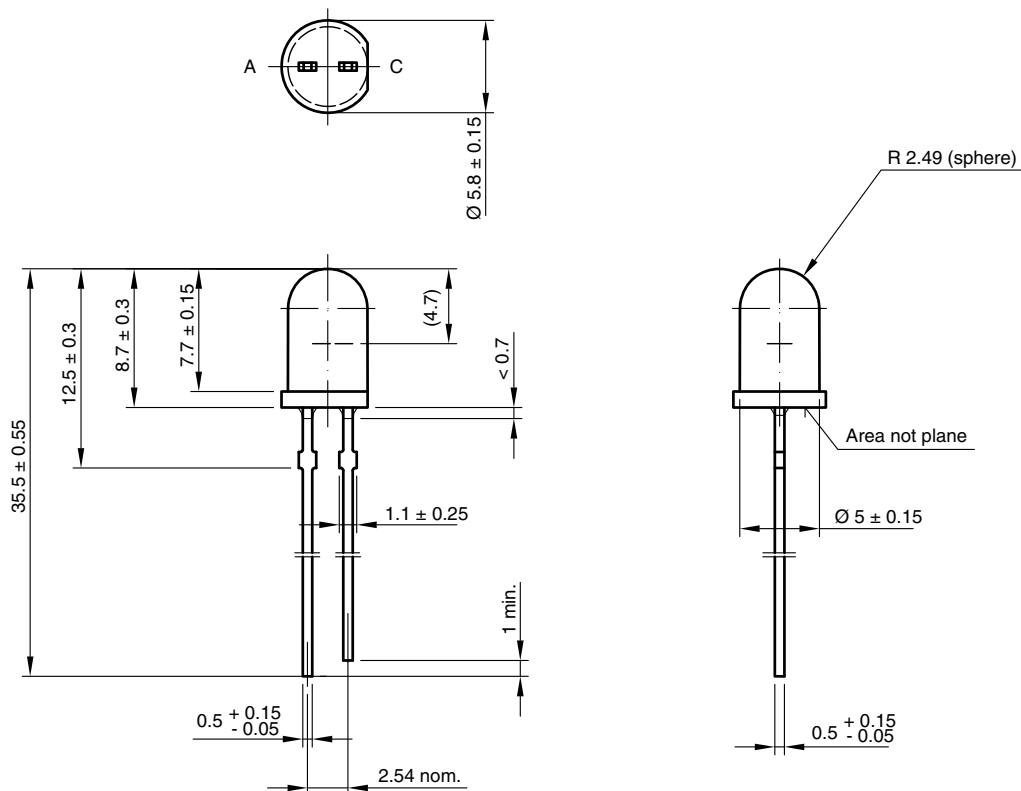


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



**PACKAGE DIMENSIONS** in millimeters



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